# NSR0320XV6T1

# **Schottky Barrier Diode**

These Schottky barrier diodes are designed for high current, handling capability, and low forward voltage performance.

## Features

- Low Forward Voltage 0.35 V (Typ) @  $I_F = 10 \text{ mAdc}$
- High Current Capability
- These are Pb–Free Devices

## **MAXIMUM RATINGS** (T<sub>J</sub> = 125°C unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Voltage	V <sub>R</sub>	23	V
Forward Power Dissipation @ $T_A = 25^{\circ}C$ Derate above 25°C	P <sub>F</sub>	200 2.0	mW mW/°C
Forward Current (DC) – Continuous	١ <sub>F</sub>	1	А
Forward Current t = 8.3 ms Half Sinewave; JEDEC Method	١ <sub>F</sub>	7.5	A
Junction Temperature	TJ	125 Max	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Characteristic	Symbol	Min	Тур	Max	Unit
Total Capacitance $(V_R = 5.0 \text{ V}, \text{ f} = 1.0 \text{ MHz})$	CT	-	30	35	pF
Reverse Leakage (V <sub>R</sub> = 15 V)	I <sub>R</sub>	-	10	50	μAdc
Forward Voltage (I <sub>F</sub> = 10 mAdc)	V <sub>F</sub>	-	0.24	0.27	Vdc
Forward Voltage (I <sub>F</sub> = 100 mAdc)	V <sub>F</sub>	_	0.30	0.35	Vdc
Forward Voltage (I <sub>F</sub> = 900 mAdc)	V <sub>F</sub>	-	0.45	0.50	Vdc

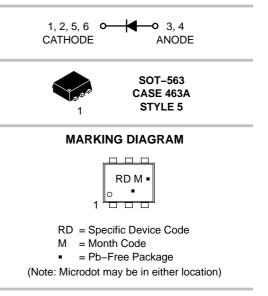
### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)



## **ON Semiconductor®**

http://onsemi.com

# HIGH CURRENT SCHOTTKY BARRIER DIODE



### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NSR0320XV6T1	SOT-563*	4000/Tape & Reel
NSR0320XV6T1G	SOT-563*	4000/Tape & Reel
NSR0320XV6T5	SOT-563*	8000/Tape & Reel
NSR0320XV6T5G	SOT-563*	8000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

\*This package is inherently Pb-Free.

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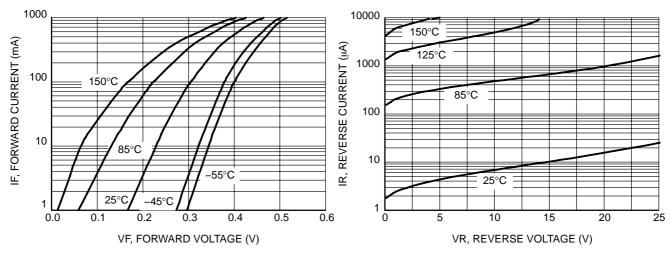




Figure 2. Leakage Current

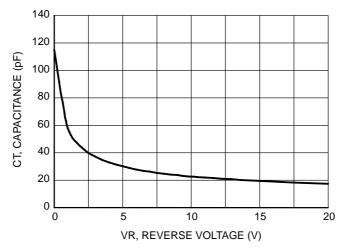
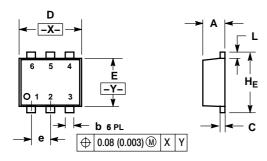


Figure 3. Total Capacitance

### NSR0320XV6T1

### PACKAGE DIMENSIONS

SOT-563, 6 LEAD CASE 463A-01 **ISSUE F** 



NOTES

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

CONTROLLING DIMENSION: MILLIMETERS MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS 3. IS THE MINIMUM THICKNESS OF BASE MATERIAL.

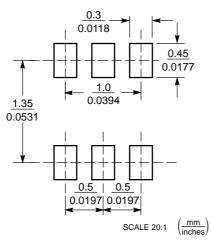
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.50	0.55	0.60	0.020	0.021	0.023
b	0.17	0.22	0.27	0.007	0.009	0.011
С	0.08	0.12	0.18	0.003	0.005	0.007
D	1.50	1.60	1.70	0.059	0.062	0.066
Е	1.10	1.20	1.30	0.043	0.047	0.051
е	0.5 BSC			0.02 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.50	1.60	1.70	0.059	0.062	0.066

STYLE 5:

- PIN 1. CATHODE 2 CATHODE
  - 3. ANODE

4. ANODE 5. CATHODE 6. CATHODE

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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